

COMPARISON OF NON-THERMAL PLASMA DECOMPOSITION CHARACTERISTICS OF ORGANO-HALIDE GASES UNDER OXIDIZING AND REDUCING ATMOSPHERE

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ABSTRACT

Halide gases used in various industrial processes significantly contribute to the greenhouse effect owing to their high GWPs. In addition, the halide gases have high chemical stability and thus remain in the atmosphere for a long period. Therefore, effective treatment techniques of halide gases are required to achieve environmental protection. The present work is concerned with the destruction of halide gases such as CF_4 , CHF_3 and $CHCIF_2$ in a wire-intube pulsed corona reactor. In details, the influence of coexisting gases of H_2 and O_2 on non-thermal plasma (NTP) decomposition of CF_4 , CHF_3 and $CHCIF_2$ was investigated. As a result, decomposition ratios of CF_4 and $CHCIF_2$ by NTP were found to be higher under H_2-N_2 atmosphere than under N_2 atmosphere. By contrast, the decomposition ratio of CHF_3 under H_2-N_2 atmosphere was lower than that under N_2 atmosphere. In the case of O_2-N_2 atmosphere than under N_2 atmosphere. Additionally, $CHCIF_2$ decomposition by NTP in the presence of O_2 yielded the reaction products such as CCI_2F_2 , $COCI_2$, COF_2 and CO_2 . Then, as the O_2 concentration increased, the formation of undesirable product of CCI_2F_2 decreased, while the generation of CO_2 increased.

KEYWORDS: non-thermal plasma, halide gases, H₂ concentration, O₂ concentration.

1. INTRODUCTION

Greenhouse gases such as CF_4 , CHF_3 and $CHCIF_2$ are widely used as organic solvents, refrigerants and dry etching agents in semiconductor industry, air conditioners and other industrial processes. However, these gases have high GWPs (Global Warming Potentials), toxicity, and may remain in the atmosphere for a long period, due to their chemical stability (Kataoka, 2001; Mizuno, 2001). Hence, the effective techniques to prevent the release of halide gases into the environment are required.

In the recent years, non-thermal plasma has been noted as one of the prospective techniques for the decomposition of halide gases (Oda *et al.*, 1996; Sathiamoorthy *et al.*, 1999). In non-thermal plasma, the decomposition process starts with dissociation and/or excitation of targeted halide molecules by direct impact of energetic electrons. Further, active radicals such as N, H, O can be formed by dissociation and ionization of background gases. Then, the initiation is followed by so called chain reactions leading to the formation of various

byproducts. The chain reactions between the radicals and halide molecules propagate until stable products are formed.

In our previous study, the plasma decomposition of dichloromethane (CH₂Cl₂) in a pulse corona reactor with and without Ca(OH)₂ alkaline absorbent under N₂ and O₂ atmosphere was performed (Huang et al., 2001). During the plasma decomposition of CH₂Cl₂ using a plasma reactor without absorbent, HCl was detected as a byproduct under N₂ atmosphere, while CO, CO₂, COCl₂ and NOx were the main byproducts found in the presence of oxygen. By contrast, when the corona reactor was combined with $Ca(OH)_2$ absorbent, HCl and $COCl_2$ were not detected during plasma decomposition of halide gases under O_2 atmosphere. In a subsequent study (Hari et al., 2002), the plasma decomposition of halide gases (CCl₄, SF₆, CHF₃ and CHCIF₂) in a plasma reactor with/without in-situ alkaline absorbent was investigated under N₂ and 2% H₂ atmospheres. At first, without *in-situ* alkaline absorbent, it was found that the decomposition ratios of SF₆, CCl₄ and CHClF₂ increased with the addition of 2% H₂ to N₂ compared to those under N₂ atmosphere alone. However, in the case of CHF₃, the decomposition ratio was lower in 2% H₂ atmosphere than that under N₂ atmosphere. Further, when non-thermal plasma was combined with in-situ Ca(OH)₂ absorption under N_2 and 2% H₂ atmospheres, the decomposition ratios of SF₆, CCl₄ and CHClF₂ were higher than those without Ca(OH)₂ absorption and products such as HCl, Cl₂, HF and F₂ were found to be effectively removed. The results of these studies indicated that the decomposition of halides and absorption of halogen (CI and F) were promoted by the formation of hydrogen halides (HCI and HF), and there was an optimum H_2 concentration for the decomposition of halide gases to form hydrogen halides. Therefore, it was of great importance to understand the behavior of plasma decomposition of halides in the presence of H_2 and O_2 .

Hence, in this study, non-thermal plasma decomposition of CF₄, CHF₃ and CHClF₂ under N₂, H₂-N₂ and O₂-N₂ atmospheres was thoroughly studied. It was considered that, in hydrogenenriched atmosphere, the halogen atoms are converted to stable hydrogen halides. On the other hand, under O₂-N₂ atmosphere, it was expected that carbon in the structure of halide gases is converted to CO₂ having lower GWP than halide gases.

2. EXPERIMENTAL

In this study, a typical wire-tube combination corona reactor was used for the experiments and the schematic diagram of experimental apparatus is shown in Figure 1.

The reactor consisted of a Pyrex glass tube with an aluminum film attached to the outer wall as the grounding electrode and a coaxial stainless steel wire as the corona wire. Using an AC power source, input voltage (5.0-9.5 kV) was applied to the wire electrode and the experiments were carried out at an input power range of 0.04-0.15 kW and at a fixed frequency of 1.0 kHz. During the experiments, no temperature adjustment was performed and the experiments were conducted at an ambient temperature.

The prepared sample gases of CF₄, CHF₃ or CHCIF₂ were introduced to the reactor at a fixed flow rate of 200 ml min⁻¹ (retention time: 68 s) in all experiments. The concentrations of CF₄, CHF₃ and CHCIF₂ in all sample gas mixtures were adjusted to 25 ppm or 100 ppm under N₂ gas, and the H₂ or O₂ concentration in the sample gases were adjusted to 0-20,000 ppm. The sample gases before and after the plasma treatment in the reactor were analyzed using an on-line FT-IR (SHIMADZU, FTIR-8700) with a gas cell of 10 cm path length. In the FT-IR measurements, the concentrations of CF₄, CHF₃, CHCIF₂, HCI, and HF gases were analyzed five times and C_{in}, C_{out}, C_{HCI}, and C_{HF} represent the average values obtained. The decomposition ratio of CF₄, CHF₃, and CHCIF₂ and the yield of HCI and/or HF from halide decomposition are defined by the following three equations:

Decomposition ratio of halides =
$$\frac{C_{\text{in}} - C_{\text{out}}}{C_{\text{in}}}$$
 (1)

Yield of HCl =
$$\frac{C_{\text{HCl}}}{(C_{\text{in}} - C_{\text{out}}) \times m}$$
 (2)

Yield of HF =
$$\frac{C_{\text{HF}}}{(C_{\text{in}} - C_{\text{out}}) \times n}$$
 (3)

where C_{in} and C_{out} [ppm] are the inlet concentration and the outlet concentration of the halide, C_{HCI} and C_{HF} are the concentrations of HCI and HF in the decomposition products. The letters *m* and *n* are the respective numbers of CI and F atoms in the halide compounds.

Regarding the decomposition of CHCIF₂, CO₂ fraction was defined as followed:

$$CO_2 \text{ fraction} = \frac{C_{CO_2}}{(C_{\text{in}} - C_{\text{out}})}$$
(4)

where C_{CO2} is the concentration of CO_2 in the decomposition products.



3. RESULTS AND DISCUSSION

3.1. Decomposition of halides by non-thermal plasma under N₂ atmosphere

Figure 2 shows the decomposition of three different halide gases (CF_4 , CHF_3 and $CHCIF_2$) as a function of power input to the plasma reactor.

As can be seen, the decomposition of halide gases started at input powers above 0.04 kW, and thus it was considered that an input power above 0.04 kW was necessary for the formation of non-thermal plasma with corona discharge in this type of reactor. Further, regarding the type of halide gas used, the decomposition of chlorine containing halide gas of $CHCIF_2$ was found to be easier than that of CF_4 and CHF_3 . In addition, the decomposition of CF_4 was found to be the most difficult to achieve.

In N_2 gas, the plasma decomposition of halide compounds was most likely initialized by dissociative electron attachment reactions generating chemically active CI and/or F atoms and followed by a chain of radical reactions to form the final products.

The products of HCI and HF, once formed by halide decomposition, did not participate in further reactions because of the relatively strong H-CI and H-F bonds. However, the CI and F atoms produced might have reacted together to form molecular CI_2 and F_2 . Given this, the major end products of plasma processing in N₂ gas were considered to be HCI, HF and F₂ for CHCIF₂; HF and F₂ for CHF₃; and F₂ for CF₄. Such a conclusion was further supported by the fact that no significant amount of organic compounds was detected by infrared spectroscopy of the decomposition products. Regarding the carbon atoms of halide gases, it was considered that carbon might have been converted to some kind of tar found coated on the electrodes in the reactor. Further, in the plasma decomposition process of CF₄, no F scavenging reactions like that of CHF₃ and CHCIF₂ decomposition occurred to form a

chemically stable hydrogen halide product. Hence, the F atoms derived from a CF_4 molecule were supposed to react with a CF_3 radical to form CF_4 again, and as a consequence, low decomposition ratios were achieved. Finally, to summarize this part, the higher decomposition ratios obtained for $CHCIF_2$ were attributed to the low bond energy of C-Cl bond (342 kJ mol⁻¹) in contrast to those of C-H and C-F bonds.



3.2. Effect of H₂ concentration on the decomposition of halides by non-thermal plasma

In the plasma decomposition of halide gases, the halogen atoms released by halide decomposition could be relatively easily converted to stable hydrogen halides, subsequently removable from the gas stream using an alkali absorbent. To achieve this goal, H₂ was introduced to the reactor and the effect of H₂ concentration on the decomposition of halides by non-thermal plasma was studied. Figure 3 shows the effect of H₂ concentration on the decomposition on the decomposition ratios of CF₄, CHF₃ and CHClF₂ at the fixed input power of 0.10 kW. In general, it can be seen that the decomposition ratio increased in order of CHClF₂ > CHF₃ > CF₄.

At first, regarding the decomposition of CF_4 , higher decomposition ratios were obtained under H_2 - N_2 atmosphere compared to decomposition ratio 0.09 obtained under N_2 atmosphere and the decomposition ratios slightly increased with an increase in H_2 concentration. It was considered that, under H_2 - N_2 atmosphere, HF was formed by recombination of F and H atoms released by plasma decomposition of CF_4 and H_2 , respectively. Then, as a consequence of HF formation, the recombination of CF_3 radical with F yielding the initial halide gas of CF_4 was assumed to be effectively hindered, which brought about higher decomposition ratios of CF_4 in the presence of H_2 .

Further, in the case of CHF₃, the CHF₃ decomposition ratio was found to significantly drop when H₂ gas was added to N₂ atmosphere, and the decomposition ratio of only about 0.4 was obtained at H₂ concentration higher than 75 ppm. Decomposition of CHF₃ was expected to be initiated by a release of H atom of the C-H bond (410 kJ mol⁻¹) rather than by a dissociation of F atom from the C-F bond (472 kJ mol⁻¹). Thus, CHF₃ decomposition mechanism in the plasma reaction field was supposed to proceed via formation of H and CF₃ radicals. However, when the H₂ gas concentration in the plasma reaction field was increased, the free H atom was recombined with CF₃ radical to form back CHF₃, and consequently the decomposition of CHF₃ was significantly reduced.

Finally, the decomposition ratio of $CHCIF_2$ increased with an increase in H₂ concentration and the decomposition ratio as high as 1.0 was achieved between 25 ppm and 510 ppm H₂. It was considered that the halogen atoms (CI and F) were converted to HCI and HF in a hydrogenenriched atmosphere, which brought about the promotion of decomposition. Although the decomposition of $CHCIF_2$ can be hindered in the presence of free H atom as in the case of

 CHF_3 , it was assumed that the decomposition proceeded in H_2 atmosphere owing to the low bond energy of C-Cl bond.

Figure 4 shows a comparison of HCl and HF yields from the decomposition of $CHClF_2$ with and without 2 % H₂ in sample gas as a function of input power. It was found that the yields of HCl and HF increased with 2 % H₂ addition to gas stream, and HCl yield of 1.0 was obtained at the input power above 0.12 kW. Such a result indicated that the hydrogen in gas stream participated in halide decomposition reactions to form the final products of HCl and HF.



in the decomposition of CHCIF₂

▲: Decomposition ratio of CHCIF₂, ■: Conversion of CI to HCI, □: Conversion of F to HF

To summarize the results presented in Figures 3 and 4, it was considered that the presence of H_2 can result in either promotion or prevention of halide gases decomposition. At first, the promotion of the decomposition occurred when the halogen atoms released from halide gases preferentially reacted with free H atom to form stable hydrogen halides. As a consequence, the back formation of an initial halide gases is likely to take place for halide gases containing an H atom in their molecule. In such a case, the presence of free H atom in the plasma reaction field could lead to a shift in the reaction equilibrium towards the initial halide gas.

3.3. Non-thermal plasma decomposition of halide gases in O₂-N₂ atmosphere

In order to achieve oxidation of carbon present in halide gases to CO₂, the non-thermal plasma decomposition of halide gases was conducted at 0.12 kW under O₂-N₂ atmosphere, of which the O₂ concentration was adjusted to 0-20,000 ppm. Figure 5 shows the decomposition ratios obtained under O₂-N₂ atmosphere for CF₄, CHF₃ and CHCIF₂. As seen in this figure, the decomposition ratio of CHF₃ decreased with an increase of O₂ concentration. The decomposition ratio of CHCIF₂ as high as 1.0 was achieved in the O₂ concentration range of 25 ppm to 2,500 ppm. However, the decomposition ratio of CHCIF₂ decreased when O₂ concentration was increased above 2,500 ppm. Finally, the decomposition of CF₄ did not take place in the whole O₂ concentration range used.

It was considered that, in the presence of O_2 in the gas stream, O radical was generated by a reaction of O_2 molecule with an electron, and consequently O_3 was formed by a reaction between O_2 and O radical. Then, as a result of these reactions, a significant portion of input energy was consumed for excitation and dissociation of O_2 molecules, which presumably led to a decrease in decomposition ratio of halide gases.



Furthermore, the reaction products of CHCIF₂ decomposition under O_2 - N_2 atmosphere were analyzed and the reaction products of COF₂, COCl₂ and desirable product of CO₂ were determined. Figure 6 shows the effect of O_2 concentration on the formation of CO₂ in nonthermal plasma decomposition of 100 ppm CHCIF₂ at 0.12 kW. It can be seen that CO₂ fraction increased with an increase in O_2 concentration, which confirmed a positive effect of O_2 on the formation of CO₂.

4. CONCLUSIONS

The effects of H_2 and O_2 concentrations on the non-thermal plasma decomposition of CF_4 , CHF_3 and $CHCIF_2$ were investigated in this study. As a result, it was found that the decompositions of CF_4 and $CHCIF_2$ were promoted by the presence of H_2 . On the other hand, the decomposition ratio of CHF_3 decreased with an increase in H_2 concentration. As for the non-thermal plasma decomposition of halides under O_2 - N_2 atmosphere, decomposition ratios of all halides employed were observed to decrease in the presence of O_2 . However, the formation of desirable end-product of CO_2 significantly increased with an increase in O_2 concentration. Finally, it was showed that the decomposition of halide gases and the formation of reaction products can be controlled by changing the reaction conditions.

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